



ELECTRONICS, INC.
 44 FARRAND STREET
 BLOOMFIELD, NJ 07003
 (973) 748-5089

NTE3881 Integrated Circuit NMOS, Parallel I/O Interface (PIO), 4MHz

Description:

The NTE3881 Parallel I/O Circuit (PIO) is a programmable, two port device which provides a TTL compatible interface between peripheral devices and the NTE3880. The Central Processing Unit (CPU) can configure the NTE3881 to interface with a wide range of peripheral devices with no other external logic required. Typical peripheral devices that are fully compatible with the NTE3881 include most keyboard, paper tape readers and punches, printers, PROM programmers, etc. The NTE3881 utilizes N channel silicon gate depletion load technology and is packaged in a 40-Lead DIP type package.

Features:

- Two Independent 8-Bit Bidirectional Peripheral Interface Ports with “Handshake” Data Transfer Control
- Interrupt Driven “Handshake” for Fast Response
- Any One of Four Distinct Modes of Operation may be Selected for a Port, including:
 - Byte Output
 - Byte Input
 - Byte Bidirectional Bus (Available on Port A Only)
 - Bit Control Mode
- All with Interrupt Controlled Handshake
- Daisy Chain Priority Interrupt Logic Included to Provide for Automatic Interrupt Vectoring without External Logic
- Eight Outputs are Capable of Driving Darlington Transistors
- All Inputs and Outputs Fully TTL Compatible
- Single 5 Volt Supply and Single Phase Clock Required

Absolute Maximum Ratings:

Temperature Under Bias	0° to +70°C
Storage Temperature Range	-65° to +150°C
Voltage On Any Pin With Respect to GND	-0.3V to +7V
Power Dissipation	6W

Note 1. Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only functional operation of the device at these or any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC Characteristics: ($T_A = 0^\circ$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Clock Input Low Voltage	V_{ILC}		-0.3	-	0.80	V
Clock Input High Voltage	V_{IHC}		$V_{CC}-0.6$	-	$V_{CC}+3$	V
Input Low Voltage	V_{IL}		-0.3	-	0.8	V
Input High Voltage	V_{IH}		2.0	-	V_{CC}	V
Output Low Voltage	V_{OL}	$I_{OL} = 2.0\text{mA}$	-	-	0.4	V
Output High Voltage	V_{OH}	$I_{OH} = -250\mu\text{A}$	2.4	-	-	V
Power Supply Current	I_{CC}		-	-	70	mA
Input Leakage Current	I_{L1}	$V_{IN} = 0$ to V_{CC}	-	-	± 10	μA
Tri-State Output Leakage Current in Float	I_{LOH}	$V_{OUT} = 2.4$ to V_{CC}	-	-	10	μA
Tri-State Output Leakage Current in Float	I_{LOL}	$V_{OUT} = 0.4\text{V}$	-	-	-10	μA
Data Bus Leakage Current in Input Mode	I_{LD}	$0 \leq V_{IN} \leq V_{CC}$	-	-	± 10	μA
Darlington Drive Current	I_{OHD}	$V_{OH} = 1.5\text{V}$ Port B Only	-1.5	-	-	mA

Capacitance: ($T_A = +25^\circ\text{C}$, $f = 1\text{MHz}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Clock Capacitance	C_ϕ	Unmeasured Pins	-	-	10	pF
Input Capacitance	C_{IN}	Input Capacitance	-	-	5	pF
Output Capacitance	C_{OUT}		-	-	10	pF

AC Characteristics: ($T_A = 0^\circ$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Clock Cycle Time	T_{cC}	Note 1	250	-	-	ns
Clock Width (High)	T_{cCH}		105	-	2000	ns
Clock Width (Low)	T_{cCL}		105	-	2000	ns
Clock Fall Time	T_{fC}		-	-	30	ns
Clock Rise Time	T_{rC}		-	-	30	ns
\overline{CE} , B/\overline{A} , C/E , to \overline{RD} , \overline{IORQ} \downarrow Setup Time	$T_{sCS}(RI)$	Note 2	50	-	-	ns
Any Hold Time for Specified Setup Time	T_h		0	-	-	ns
\overline{RD} , \overline{IORQ} to Clock \uparrow Setup Time	$T_{sRI}(C)$		115	-	-	ns
\overline{RD} , \overline{IORQ} \downarrow to Data Out Delay	$T_{dRI}(DO)$	Note 3	-	-	380	ns
\overline{RD} , \overline{IORQ} \uparrow to Data Out Float Delay	$T_{dRI}(DO_r)$		-	-	110	ns
Data In to Clock \uparrow Setup Time	$T_{sDI}(C)$	$C_L = 50\text{pF}$	50	-	-	ns
\overline{IORQ} \downarrow to Data Out Delay (INTA Cycle)	$T_{dIO}(DOI)$	Note 4	250	-	-	ns
$\overline{M1}$ \downarrow to Clock \uparrow Setup Time	$T_{sM1}(Cr)$		90	-	-	ns
$\overline{M1}$ \uparrow to Clock \downarrow Setup Time ($\overline{M1}$ Cycle)	$T_{sM1}(Cf)$		0	-	-	ns

Note 1 $T_{cC} = T_{wCh} + T_{wCl} + T_{rC} + T_{fC}$.

Note 2. $T_{sCS}(RI)$ may be reduced. However, the time subtracted from $T_{sCS}(RI)$ will be added to $T_{dR}(DO)$.

Note 3. Increase $T_{dRI}(DO)$ by 10ns for each 50pF increase in loading up to 200pF max.

Note 4. Increase $T_{dIO}(DOT)$ by 10ns for each 60pF increase in loading up to 200pF max.

